# **Dual DPDT Low R<sub>ON</sub>, Low Capacitance Switch**

The NLAS3899B is a dual DPDT analog switch designed for low power audio and dual SIM card applications. The low  $R_{ON}$  of 3.0  $\Omega$  (typical) is ideal for routing audio signals to or from a moderately high impedance load. In addition, the low  $C_{ON}$  of 20 pF (typical) gives the NLAS3899B a high bandwidth of 280 MHz, perfect for dual SIM card applications.

#### **Features**

- Single Supply Operation
   1.65 to 4.3 V V<sub>CC</sub>
   Function Directly from Li–Ion Battery
- Low ON Resistance (3.0 Ω Typical Across V<sub>CC</sub>)
- Low C<sub>ON</sub> (20 pF Typical)
- Bandwidth 280 MHz
- Maximum Breakdown Voltage: 5.5 V
- Low Static Power
- Interfaces with 1.8 V Chipset
- These are Pb-Free Devices

#### **Typical Applications**

- Cell Phone Speaker/Microphone Switching
- Ringtone-Chip/Amplifier Switching
- Dual SIM Card Data Switching
- Four Unbalanced (Single-Ended) Switches

## Important Information

• ESD Protection:

Human Body Model (HBM) 1000 V – All Pins 5000 V – I/O to GND

- Continuous Current Rating Through each Switch ±300 mA
- Conforms to: JEDEC MO-220, Issue H, Variation VEED-6
- Package:
  - 1.8 x 2.6 x 0.75 mm WQFN16 Pb-Free
  - 3.0 x 3.0 x 0.9 mm QFN16 Pb-Free

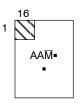


## ON Semiconductor®

http://onsemi.com

#### MARKING DIAGRAMS







QFN16 CASE 485AE

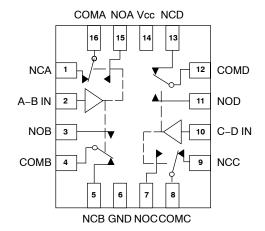


XX = Specific Device CodeA = Assembly Location

 $\overline{M}$  = Date Code/Assembly Location

L = Wafer Lot
Y = Year
W = Work Week
= Pb-Free Package

(Note: Microdot may be in either location)



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

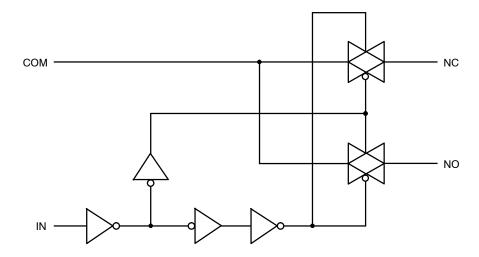


Figure 1. Input Equivalent Circuit

#### **PIN DESCRIPTION**

QFN PIN #	Symbol	Name and Function
1, 3, 5, 7, 9, 11, 13, 15	NO A-D, NC A-D	Independent Channels
2, 10	A-B IN, C-D IN	Controls
4, 8, 12, 16	COM A-D	Common Channels
6	GND	Ground (V)
14	V <sub>CC</sub>	Positive Supply Voltage

## **TRUTH TABLE**

IN	NO	NC
Н	ON	OFF*
L	OFF*	ON

<sup>\*</sup>High impedance.

## **OPERATING CONDITIONS**

## **MAXIMUM RATINGS**

Symbol	Pins	Parameter	Value	Condition	Unit
V <sub>CC</sub>	V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +5.5		V
V <sub>IS</sub>	NOx, NCx, or COMx	Analog Signal Voltage	–0.5 to V <sub>CC</sub> + 0.5		V
V <sub>IN</sub>	A-B IN, C-D IN	Control Input Voltage	-0.5 to 5.5		V
I <sub>IS_CON</sub>	NOx, NCx, or COMx	Analog Signal Continuous Current	±300	Closed Switch	mA
I <sub>IS_PK</sub>	NOx, NCx, or COMx	Analog Signal Peak Current	±500	10% Duty Cycle	mA
I <sub>IN</sub>	A-B IN, C-D IN	Control Input Current	±20		mA
T <sub>STG</sub>		Storage Temperature Range	-65 to 150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Pins	Parameter	Value	Condition	Unit
V <sub>CC</sub>	V <sub>CC</sub>	Positive DC Supply Voltage	1.65 to 4.3		V
V <sub>IS</sub>	NOx, NCx, or COMx	Analog Signal Voltage	GND to V <sub>CC</sub>		V
V <sub>IN</sub>	A-B IN, C-D IN	Control Input Voltage	GND to 4.3		V
T <sub>A</sub>		Operating Temperature Range	-40 to +85		°C
t <sub>r</sub> , t <sub>f</sub>		Input Rise or Fall Time	20	V <sub>CC</sub> = 1.6 V – 2.7 V	ns/V
			10	V <sub>CC</sub> = 3.0 V - 4.5 V	

Minimum and maximum values are guaranteed through test or design across the **Recommended Operating Conditions**, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for each section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.

## **ESD PROTECTION**

Pins	Description	Minimum Voltage
All Pins	Human Body Model	1 kV
I/O to GND	Human Body Model	5 kV

## **DC Electrical Characteristics**

Typical: T =  $25^{\circ}$ C;  $V_{CC}$  = 3.0 V

## **CONTROL INPUT** (Typical: T = $25^{\circ}$ C; $V_{CC} = 3.0 \text{ V}$ )

				V <sub>cc</sub>	-40°C to +85°C			
Symbol	Pins	Parameter	Test Conditions	(V)	Min	Тур	Max	Unit
V <sub>IH</sub>	A-B IN, C-D IN	Control Input High		3.0 4.3	1.3 1.6			V
V <sub>IL</sub>	A-B IN, C-D IN	Control Input Low		3.0 4.3			0.5 0.6	V
I <sub>IN</sub>	A-B IN, C-D IN	Control Input Leakage	$0 \le V_{IN} \le V_{CC}$	4.3		±0.1	±1.0	μΑ

## SUPPLY CURRENT AND LEAKAGE (Typical: T = $25^{\circ}$ C; $V_{CC} = 3.0 \text{ V}$ )

				V <sub>CC</sub>	-40°C to +85°C			
Symbol	Pins	Parameter	Test Conditions	(V)	Min	Тур	Max	Unit
I <sub>NO/NC</sub> (OFF)	NCx, NOx	OFF State Leakage	$ \begin{aligned} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ V_{NC/NO} &= 0.3 \text{ V} \\ V_{COM} &= 4.0 \text{ V} \end{aligned} $	4.3		±10	±300	nA
I <sub>COM</sub> (ON)	COMx	ON State Leakage	$\begin{aligned} &V_{IN} = V_{IL} \text{ or } V_{IH} \\ &V_{NO} = 0.3 \text{ V or } 4.0 \text{ V with} \\ &V_{NC} \text{ floating or} \\ &V_{NC} = 0.3 \text{ V or } 4.0 \text{ V with} \\ &V_{NO} \text{ floating} \\ &V_{COM} = 0.3 \text{ V or } 4.0 \text{ V} \end{aligned}$	4.3		±10	±300	nA
I <sub>CC</sub>	V <sub>CC</sub>	Quiescent Supply	$V_{IN}$ and $V_{IS} = V_{CC}$ or GND $I_D = 0$ A	1.65 – 4.3		±1.0	±2.0	μΑ
l <sub>OFF</sub>	A-B IN, C-D IN	Power Off Leakage	V <sub>IN</sub> = 4.3 V or GND	0		±0.5	±2.0	μА

## **ON RESISTANCE** (Typical: $T = 25^{\circ}C$ ; $V_{CC} = 3.0 \text{ V}$ )

				V <sub>CC</sub>	-40°C to +85°C			
Symbol	Pins	Parameter	Test Conditions	(V)	Min	Тур	Max	Unit
R <sub>ON</sub>	NOx, NCx COMx	ON Resistance	$I_{ON} = -100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	2.5 3.0 3.6 4.3		3.0 2.6 2.5 2.2	4.0 3.0 3.0 2.5	Ω
R <sub>FLAT</sub>	NOx, NCx COMx	R <sub>ON</sub> Flatness	I <sub>ON</sub> = -100 mA V <sub>IS</sub> = 0 to V <sub>CC</sub>	3.0 4.3		0.8 1.1		Ω
$\Delta R_{ON}$	NOx, NCx COMx	R <sub>ON</sub> Matching	I <sub>ON</sub> = -100 mA V <sub>IS</sub> = 0 to V <sub>CC</sub>	3.0 4.3		0.8 0.7		Ω

## **AC ELECTRICAL CHARACTERISTICS**

**TIMING/FREQUENCY** (Typical: T = 25°C;  $V_{CC}$  = 3.0 V,  $R_L$  = 50  $\Omega$ ,  $C_L$  = 35 pF, f = 1 MHz)

				v <sub>cc</sub>	-40°C to +85°C			
Symbol	Pins	Parameter	Test Conditions	(V)	Min	Тур	Max	Unit
t <sub>ON</sub>	IN to NCx or NOx	Turn On Time		2.3 – 4.3		30	40	ns
t <sub>OFF</sub>	IN to NCx or NOx	Turn Off Time		2.3 – 4.53		20	30	ns
t <sub>BBM</sub>	IN to NCx or NOx	Break Before Make		3.0	2	15		ns
BW		-3dB Bandwidth	C <sub>L</sub> = 5 pF	1.65 – 4.3		280		MHz

## **ISOLATION AND THD** (Typical: T = 25°C; $V_{CC}$ = 3.0 V, RL = 50 $\Omega$ , CL = 5 pF, f = 1 MHz)

				V <sub>CC</sub>	-40	0°C to +85	°C	
Symbol	Pins	Parameter	Test Conditions	(V)	Min	Тур	Max	Unit
Q		Charge Injection	$\begin{aligned} &V_{IN} = V_{CC} \text{ to GND} \\ &R_{IS} = 0 \ \Omega, \ C_L = 1.0 \ nF \\ &Q = C_L - \Delta V_{OUT} \end{aligned}$	1.65 – 4.3		111		pC
THD		Total Harmonic Distortion	$\begin{aligned} F_{ S} &= 20 \text{ Hz to } 20 \text{ kHz} \\ R_L &= R_{gen} = 600 \ \Omega, \\ C_L &= 1.0 \text{ pF} \\ V_{ S} &= 1.0 \text{ V}_{PP} \end{aligned}$	3.0		0.007		%
V <sub>ONL</sub>		Maximum Feed- through On Loss	$V_{\text{IN}}$ = 0 dBm @ 100 kHz to 50 MHz $V_{\text{IN}}$ centered between $V_{\text{CC}}$ & GND	1.65 – 4.3		-0.06		dB
O <sub>IRR</sub>	NOx	Off Isolation	$V_{IN} = 0$ $V_{NO}$ or $V_{NC}$ (pk-pk) = 1.0 V	1.65 – 4.3		-67		dB
Xtalk	COMx to COMy	Non-Adjacent Chan- nel	$V_{NO}$ or $V_{NC}$ (pk-pk) = 1.0 V	1.65 – 4.3		-100		dB

## $\textbf{CAPACITANCE} \text{ (Typical: } T = 25^{\circ}\text{C; V}_{CC} = 3.0 \text{ V, R}_{L} = 50 \text{ }\Omega\text{, C}_{L} = 5 \text{ pF, f} = 1 \text{ MHz)}$

				V <sub>CC</sub>	-40°C to +85°C			
Symbol	Pins	Parameter	Test Conditions	(V)	Min	Тур	Max	Unit
C <sub>IN</sub>	A-B IN, C-D IN	Control Input		0 V		5.0		pF
C <sub>ON</sub>	NCx to COMx	Through Switch	V <sub>IN</sub> = 0V	3.0 V		20		pF
C <sub>OFF</sub>	NCx NOx	Unselected Port	$V_{IS} = 3.0V, V_{IN} = 3.0V$	3.0 V		10		pF

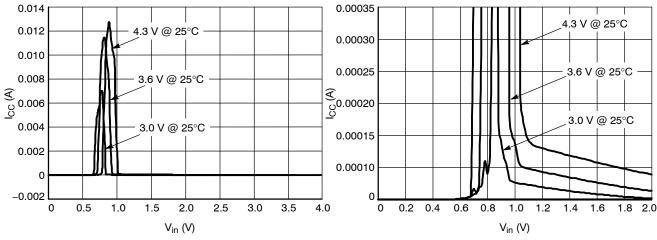
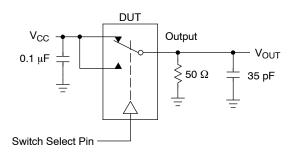


Figure 2. I<sub>CC</sub> vs. V<sub>in</sub>

Figure 3. (Expanded View)  $I_{CC}$  vs.  $V_{in}$ 



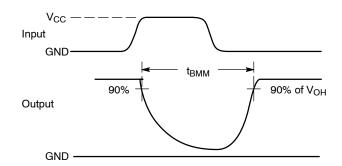
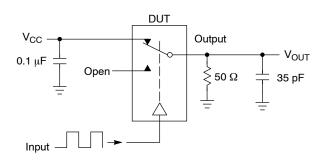


Figure 4. t<sub>BBM</sub> (Time Break-Before-Make)



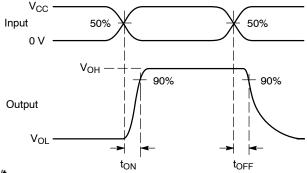
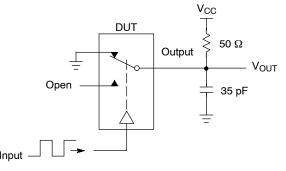


Figure 5.  $t_{ON}/t_{OFF}$ 



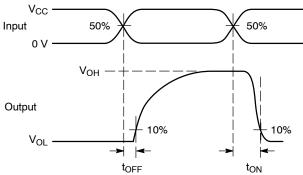
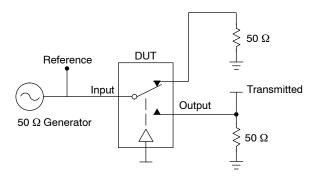


Figure 6. t<sub>ON</sub>/t<sub>OFF</sub>



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{\rm ISO}$ , Bandwidth and  $V_{\rm ONL}$  are independent of the input signal direction.

$$\begin{split} &V_{ISO} = \text{Off Channel Isolation} = 20 \text{ Log } \left(\frac{V_{OUT}}{V_{IN}}\right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \\ &V_{ONL} = \text{On Channel Loss} = 20 \text{ Log } \left(\frac{V_{OUT}}{V_{IN}}\right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below  $V_{ONL}$ 

 $V_{CT}$  = Use  $V_{ISO}$  setup and test to all other switch analog input/outputs terminated with 50  $\Omega$ 

Figure 7. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V<sub>ONL</sub>

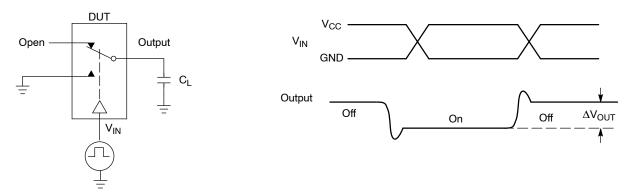


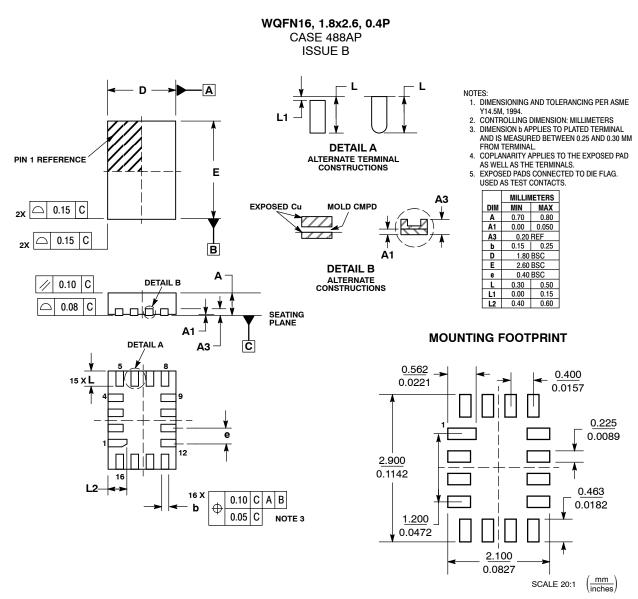
Figure 8. Charge Injection: (Q)

## **DEVICE ORDERING INFORMATION**

Device Order Number	Package Type	Tape & Reel Size <sup>†</sup>
NLAS3899BMNTBG	WQFN16 (Pb-Free)	3000 / Tape & Reel
NLAS3899BMNTWG	QFN16 (Pb-Free)	3000 / Tape & Reel
NLAS3899BMNTXG	QFN16 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

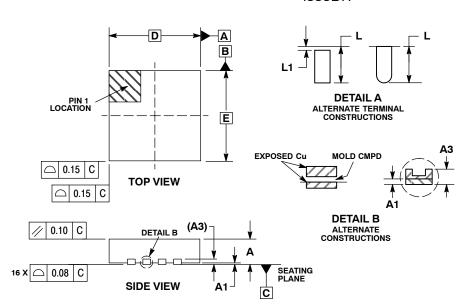
#### PACKAGE DIMENSIONS



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

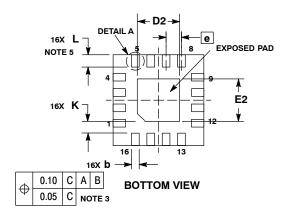
#### QFN16 3x3, 0.5 P CASE 485AE ISSUE A



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M. 1994.
- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- COPIN OBLING DIMENSION. WILLING FERS.
   DIMENSION 5 APPLIES TO PLATED
   TERMINAL AND IS MEASURED BETWEEN
   0.25 AND 0.30 MM FROM TERMINAL
   COPLANARITY APPLIES TO THE EXPOSED
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
   OUTLINE MEETS JEDEC DIMENSIONS PER
- OUTLINE MEETS JEDEC DIMENSIONS PER MO-220, VARIATION VEED-6.

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	0.80	0.90	1.00
A1	0.00	0.03	0.05
A3	0.20 REF		
b	0.18	0.25	0.30
D	3.00 BSC		
D2	1.25	1.40	1.55
E	3.00 BSC		
E2	1.25	1.40	1.55
е	0.50 BSC		
K	0.20		
L	0.30	0.40	0.50
L1	0.00		0.15



ON Semiconductor and the registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunit

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

**Phone**: 303-675-2175 or 800-344-3860 Toll Free USA/Canada **Fax**: 303-675-2176 or 800-344-3867 Toll Free USA/Canada

Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative